	1 A A A A A A A A A A A A A A A A A A A
ΡΛΝ	JIT
	SEMI
	CONDUCTOR

60V N-Channel Enhancement Mode MOSFET

Current

Features

Voltage

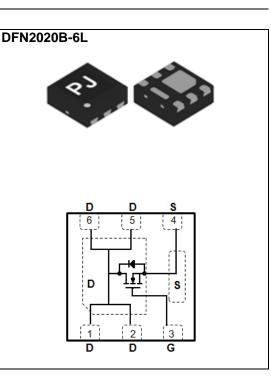
• RDS(ON) , VGS@10V, ID@3.2A<75mΩ

60 V

- Rds(on) , Vgs@4.5V, Id@2.0A<90m Ω
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN2020B-6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0086 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

3.2A

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	60	V
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V
Continuous Drain Current		ID	3.2	А
Pulsed Drain Current		I _{DM}	12.8	А
Power Dissipation	T _a =25°C		2.0	W
	Derate above 25°C	PD	16	mW/ºC
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	°C
Typical Thermal Resistance - Junction to Ambient, t<10s (Note 3)		R _{eja}	62.5	°C/W



Electrical Characteristics (T_A=25°C unless otherwise noted)

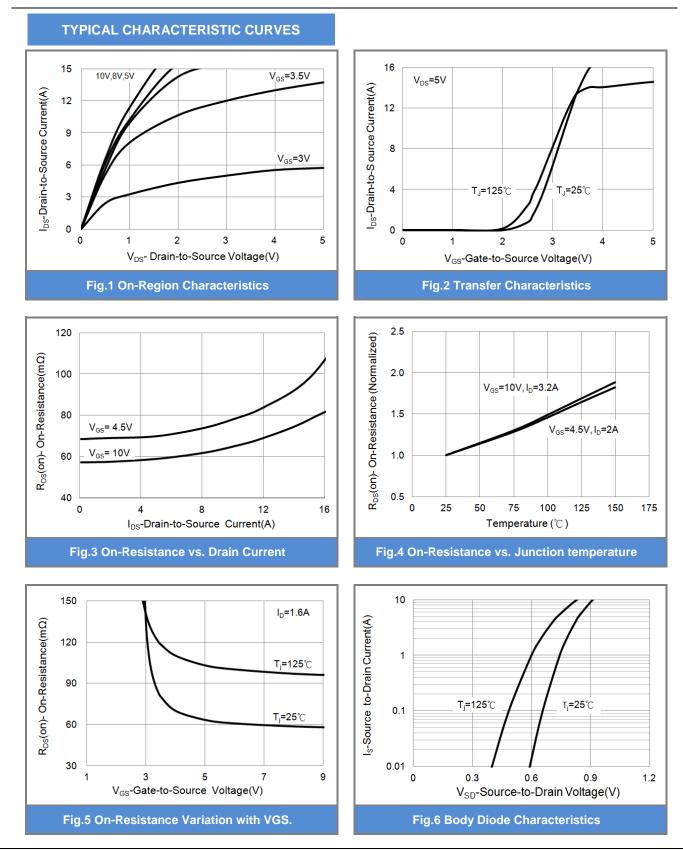
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	60	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1.0	1.8	2.5	V
Drain-Source On-State Resistance		Vgs=10V, Id=3.2A	-	53	75	mΩ
	$R_{DS(on)}$	V _{GS} =4.5V, I _D =2.0A	-	61	90	
Zero Gate Voltage Drain Current	IDSS	V _{DS} =48V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	lgss	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)		-		_		_
Total Gate Charge	Qg		-	9.3	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =48V, I _D =3.0A, V _{GS} =10V (Note 1,2)	-	2.2	-	
Gate-Drain Charge	Q _{gd}		-	1.9	-	
Input Capacitance	Ciss		-	509	-	pF
Output Capacitance	Coss	V _{DS} =15V, V _{GS} =0V, f=1.0MHZ	-	47	-	
Reverse Transfer Capacitance	Crss		-	23	-	
Turn-On Delay Time	td _(on)	$V_{DD}=30V, I_{D}=3.0A,$ $V_{GS}=10V,$ $R_{G}=3.3\Omega$ ^(Note 1,2)	-	3.2	-	
Turn-On Rise Time	tr		-	9.7	-	ns
Turn-Off Delay Time	td _(off)		-	18.5	-	
Turn-Off Fall Time	tf	RG=3.312 (Note 1,2)	-	6.4	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	1-		_	-	3.2	А
Diode Forward Current	ls		-	-	3.2	
Diode Forward Voltage	V _{SD}	Is=1A, V _{GS} =0V	-	0.75	1.2	V

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. R_{®JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.



PJQ2460





PJQ2460

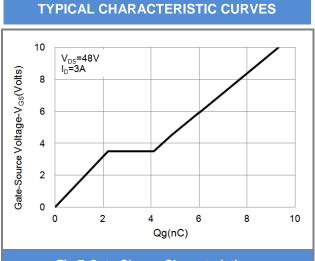
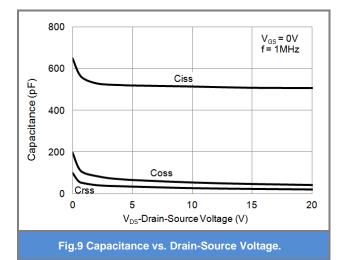


Fig.7 Gate-Charge Characteristics



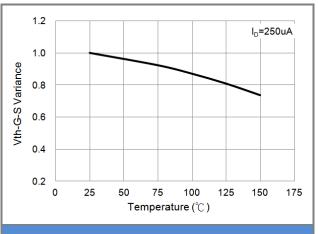
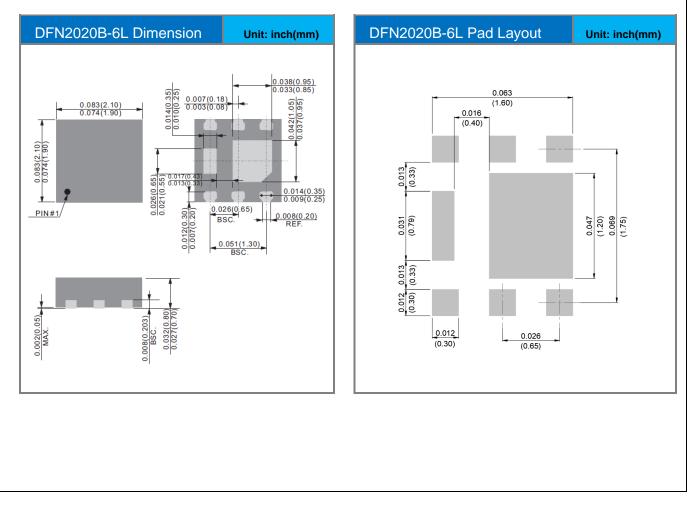


Fig.8 Threshold Voltage Variation with Temperature.



Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ2460_R1_00001	DFN2020B-6L	3K pcs / 7" reel	460	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout







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